

Absorption Studies in Sapphire

LIGO-G010152-00-Z

A. Alexandrovski, R. K. Route, M. M. Fejer
E. L. Ginzton Laboratory
Stanford University

fejer@leland.stanford.edu

Why Do We Care?

Imperfect materials \Rightarrow absorption

Absorption \Rightarrow inhomogeneous temperature rise

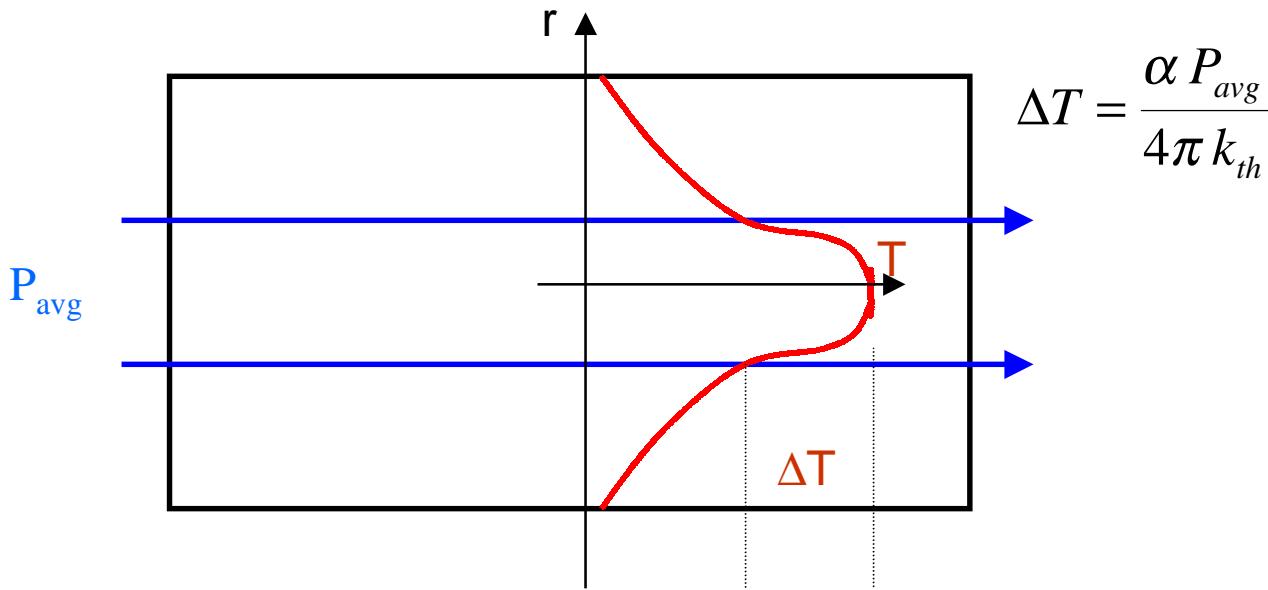
Temperature rise \Rightarrow thermal expansion, change in refractive index

Distorted optic \Rightarrow distorted wavefront

- Implications for IF design
 - limits allowable power on various elements
 - influences cavity stability through power range
- Options
 - transmissive optics
 - low loss materials
 - clever IF design
 - active thermal compensation
 - reflective designs
 - e.g. Beyersdorf talk

Temperature Rise in Absorbing Medium

- Absorbed optical power inhomogeneously heats crystal
 - produces radially varying temperature
 - produces optical distortion due to photothermal effects



- Temperature rise across beam *independent* of spot size
- Leads to radially varying index: $\Delta n = dn/dT \Delta T$
- Leads to radially varying phase on optical beam:
- Similarly get a bump on surface:
 - κ = thermal expansion coeff.

$$\Delta\phi : \frac{\alpha \kappa}{2k_{th}\lambda} L P_{avg}$$

$$\Delta\phi \sim \frac{\alpha dn/dT}{2k_{th}\lambda} L P_{avg}$$

Requirements

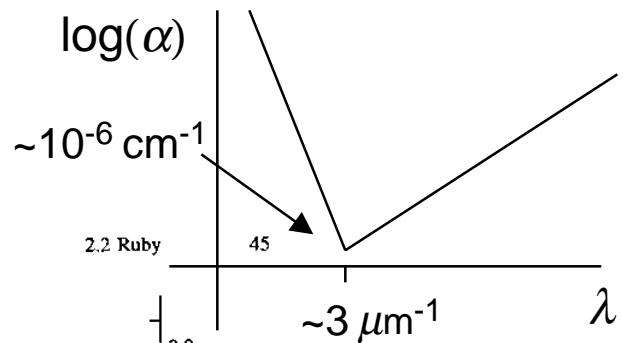
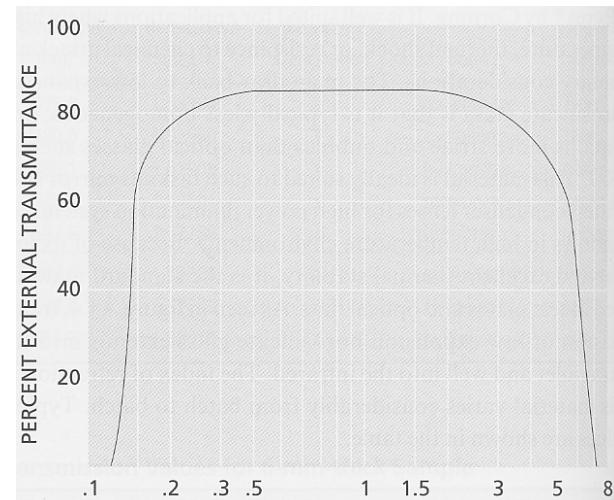
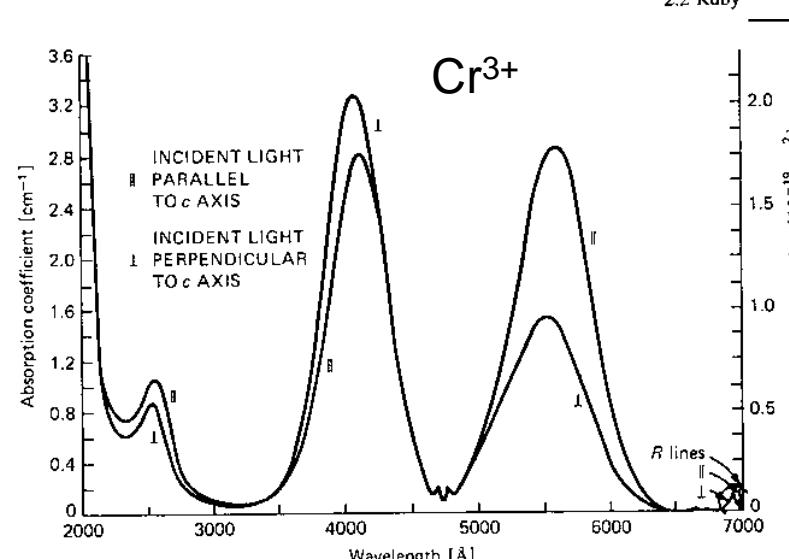
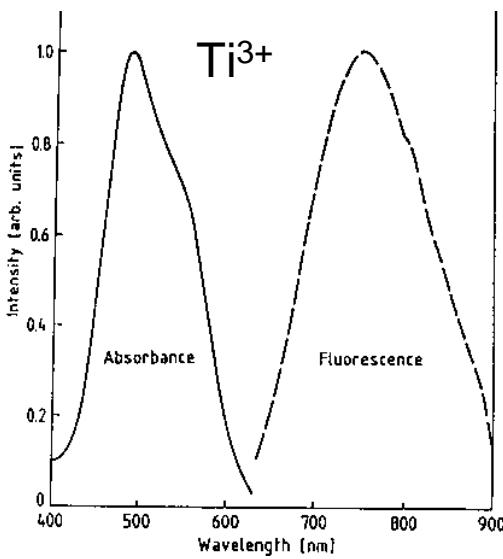
- Intrinsic and extrinsic material properties combine to determine distortion
 - transmission FOM:
$$FOM \sim \frac{k_{th}}{\alpha dn/dT}$$
 - reflection from absorbing substrate:
$$FOM \sim \frac{k_{th}}{\alpha \kappa}$$
- For LIGO II
 - ~ 10 ppm/cm \Rightarrow OK
 - ~ 40 ppm/cm \Rightarrow with active thermal compensation
- Currently: 40 ppm/cm in large samples
 - isolated observations at 10 ppm/cm level

Outline

- Absorption characteristics in sapphire
- Absorption measurements
- Crystal Growth
- Sample Sets
 - growth studies
 - annealing studies
- Observations and Trends
- Status and Plans

Absorption in Sapphire

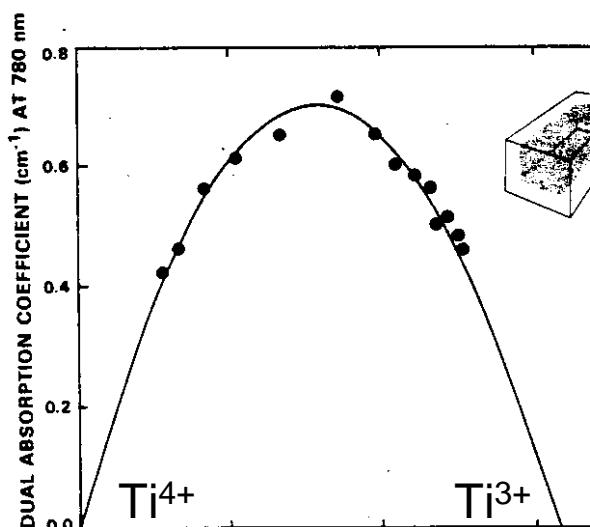
- Intrinsic
 - conduction to valence band in UV
 - multiphonon in mid-IR
 - only cure is different material
 - expectation and existence proofs indicate this isn't the problem
- Extrinsic
 - native defects
 - vacancies, antisites, interstitials,
 - impurities
 - e.g. transition metals: Cr, Ti, Fe, ...



Characteristics of Absorbing Species

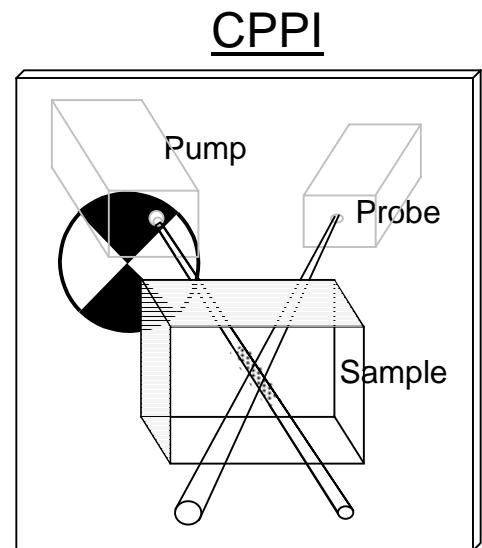
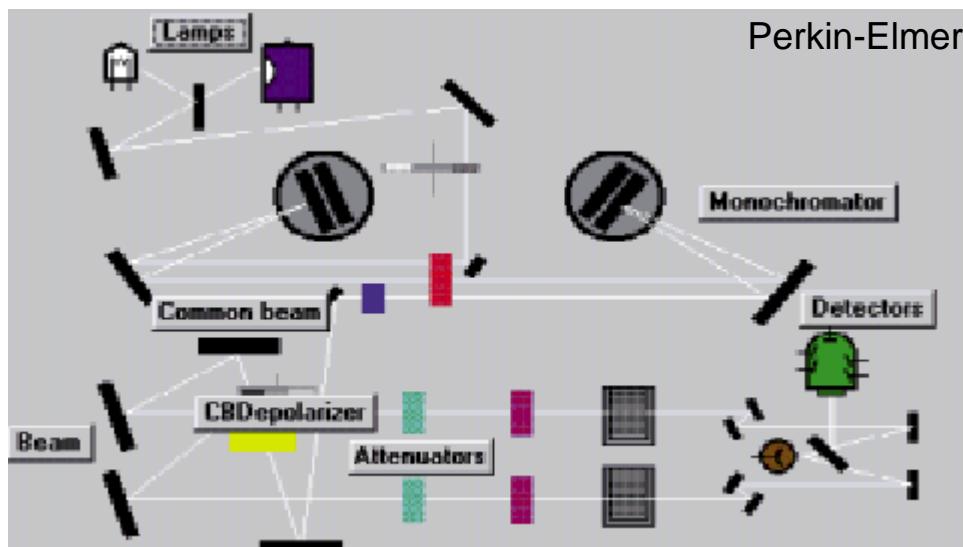
- Allowed transitions
 - large cross sections \Rightarrow ppm concentrations significant
- Broad spectral features
 - identification difficult
 - off “resonant” absorption significant
 - sum of several species can contribute to absorption at given λ
- Redox state important
 - e.g. $\alpha[\text{Ti}^{3+}] \neq \alpha[\text{Ti}^{4+}]$
 - annealing alters absorption without altering impurity concentrations
- Impurities do not necessarily act independently
 - Al : Al : Ti³⁺ : Ti⁴⁺ : Al : Al \neq Al : Ti³⁺ : Al : Al : Ti⁴⁺ : Al
 - absorption spectra at high concentrations not always same as low complicates correlations to known spectra

$$\Rightarrow \alpha_{IR} \propto [\text{Ti}^{3+}][\text{Ti}^{4+}]$$



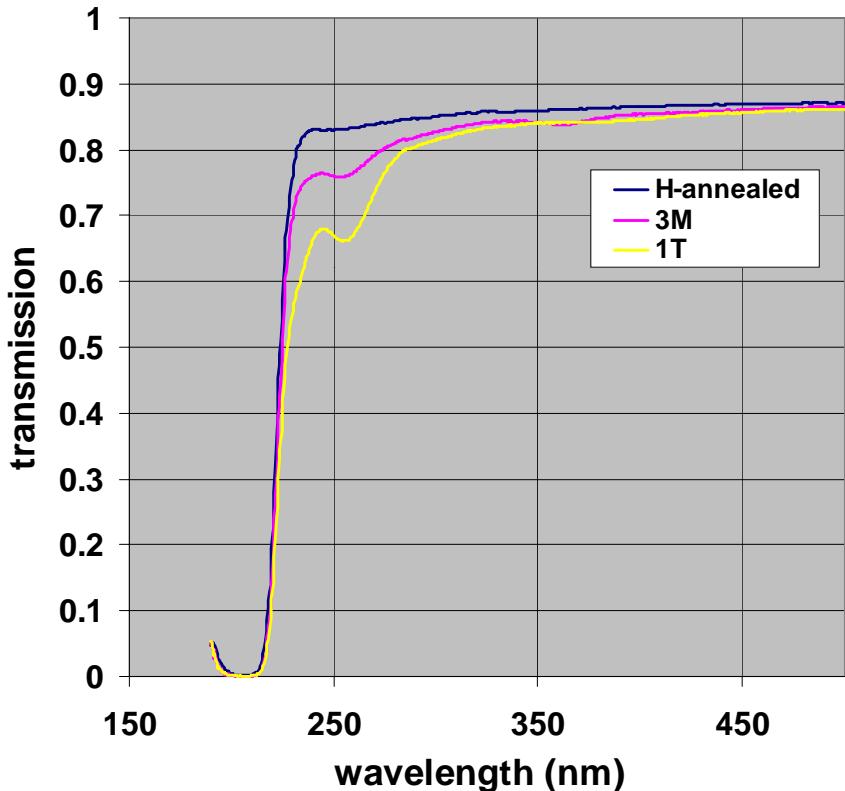
Absorption Measurement

- Spectrophotometer
 - broad continuous wavelength coverage (UV – IR)
 - difficult to resolve below 10^{-3} absorption
reflections and interference also influence transmission especially for broad features
 - no spatial resolution
gives line-integrated absorption
- Common-path photothermal interferometry (Alexometry)
 - spatially resolved (< 0.5 mm)
 - sensitive (~ 1 ppm/cm absorption)
 - requires laser, so wavelength coverage not continuous
 $1.06\text{ }\mu\text{m}$, $0.532\text{ }\mu\text{m}$, $0.514\text{ }\mu\text{m}$, $0.488\text{ }\mu\text{m}$, ...

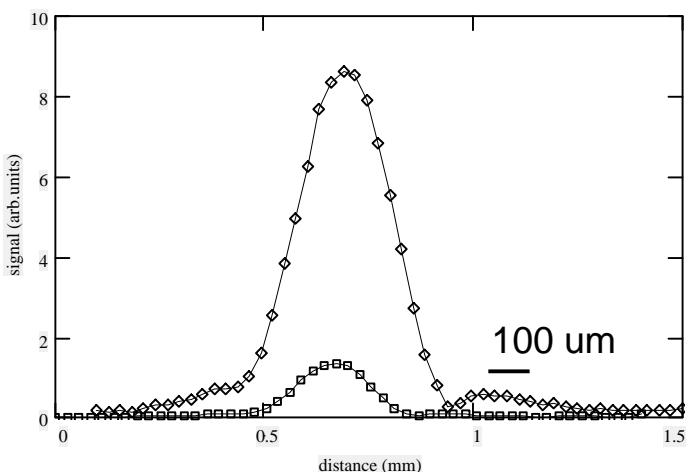
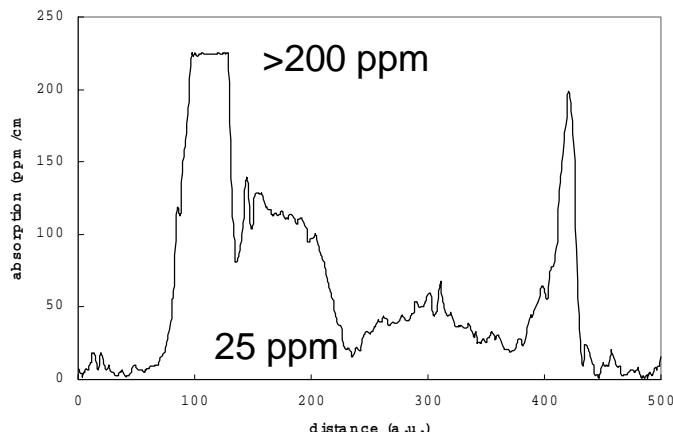
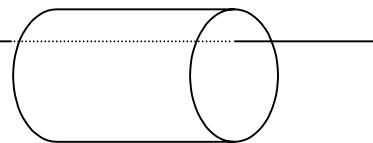


Typical Spectra

Various Al_2O_3 Samples



longitudinal scan
in Al_2O_3

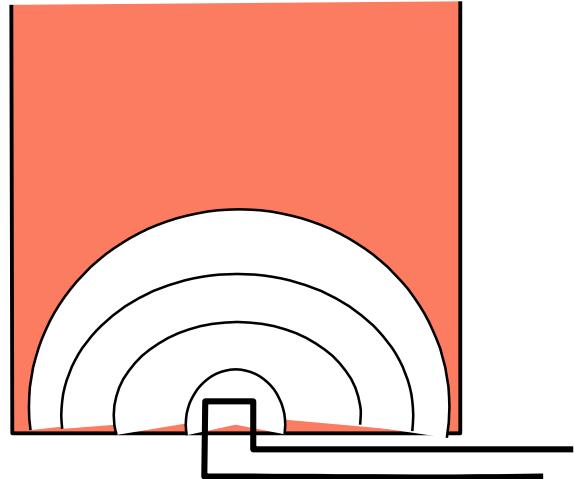


Scan through electroded Al_2O_3

- trace 1: 100A-thick electrode
- trace 2: 1200A-thick electrode

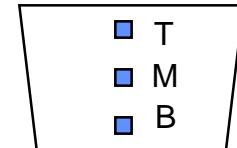
HEM Crystal Growth

- Heat Exchanger Method
 - He-gas cools bucket of melt
 - solidification outwards from bottom
- Starting materials
 - typically “craquelle” sapphire
 - ppm levels of some transition metals
 - purity $\uparrow \Rightarrow \$ \uparrow\uparrow$
- Segregation
 - impurities rejected ($k < 1$) into melt
 - segregate into outer regions of crystal (last to crystallize)
 - can expect different behavior top/middle/bottom of boule
 - can remelt outer portion to concentrate impurities
 - remelt inner portion to reduce impurity concentration
 - opposite argument for $k > 1$ impurities



Samples

- Experimental design
 - anticipated mechanisms: impurity concentration, intrinsic defects, redox state
 - two main control methods: growth and annealing
- Growth Studies
 - ~ 30 CSI White, 1 cm cubes
 - primarily expected to influence impurity concentration
 - starting materials
 - virgin material from 5 different vendors/purity
 - remelted boules
 - samples cut from top/middle/bottom of boule
 - explore impurity segregation effects
- Annealing Studies
 - 2.5 cm dia x 1 cm thick a-axis Hemex CSI White
 - primarily influence redox state, intrinsic defects (e.g. Oxygen vacancies)
 - parameters: time, temperature, reducing (H_2) or oxidizing (air, O_2)
 - furnace design
 - accidental introduction of impurities, especially near surface
- Occasional samples
 - large CSI samples
 - from coating or Q tests
 - SIOM crystals

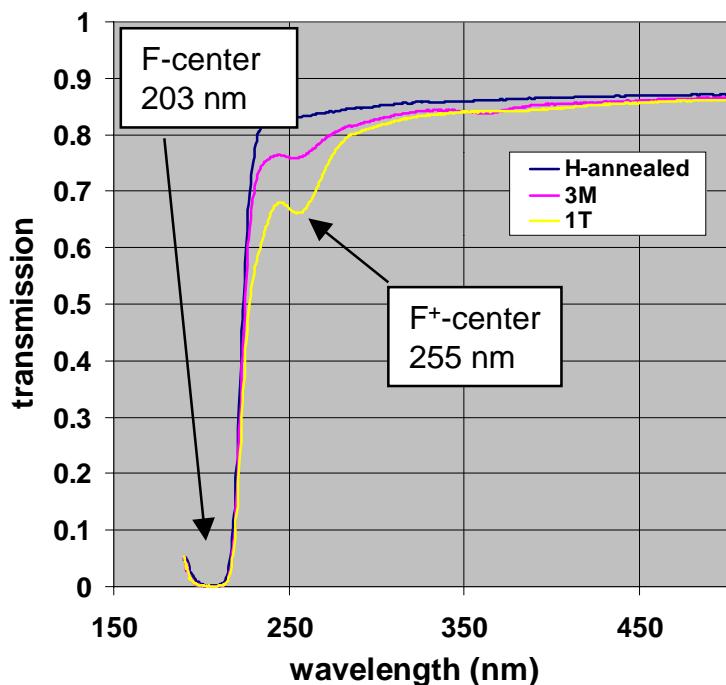


Composition Analysis (GDMS)

	LIGO #1T Sample #10 ppmw	LIGO #1M Sample #11 ppmw	LIGO #1B Sample #12 ppmw	LIGO #2T Sample #07 ppmw	LIGO #2M Sample #08 ppmw	LIGO #2B Sample #09 ppmw	LIGO #3T Sample #04 ppmw	LIGO #3M Sample #05 ppmw	LIGO #3B Sample #06 ppmw	LIGO #4T Sample #01 ppmw	LIGO #4M Sample #02 ppmw	LIGO #4B Sample #03 ppmw	LIGO #5T Sample #13 ppmw	LIGO #5M Sample #14 ppmw	LIGO #5B Sample #15 ppmw	LIGO #6T Sample #16 ppmw
Li	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05
Be	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05
O	Major															
F	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1
Na	0.21	0.42	0.40	0.25	0.75	0.35	0.36	0.44	0.81	0.82	3.2	0.95	0.20	0.26	0.26	0.46
Mg	0.16	0.27	0.30	0.22	0.29	0.18	0.19	0.25	0.25	0.53	0.39	0.20	0.15	0.15	0.10	0.065
Al	Major															
Si	12	8.5	10	8.5	7.5	9.5	4.2	5.9	9.5	10	15	8.5	15	7.5	6.9	11
P	0.1	0.053	0.20	0.11	0.11	0.11	0.1	0.15	0.15	0.21	0.19	0.1	0.045	0.045	0.13	0.14
S	1.1	1.5	1.8	0.79	1.2	1.6	1.5	1.5	0.21	1.5	1.8	1.1	0.88	0.60	1.6	1.1
Cl	1.2	5.5	4.2	1.5	2.5	2.5	2.6	2.9	3.1	4.7	6.0	1.0	2.5	1.7	1.5	3.9
K	0.29	0.25	0.39	0.33	0.33	0.35	0.23	0.35	0.33	1.1	1.2	0.40	0.25	0.23	0.21	0.38
Ca	1.1	1.2	1.1	1.1	1.1	1.5	1.2	0.63	0.75	1.7	1.4	0.75	0.80	0.86	1.0	0.82
Ti	0.37	0.11	0.45	0.12	0.36	0.45	0.089	0.39	0.27	0.22	0.14	0.12	0.11	0.19	0.081	0.25
V	0.10	0.037	0.026	0.12	0.23	0.37	0.026	0.021	0.04	0.11	0.086	0.095	0.056	0.072	0.066	0.086
*Cr	2.5	1.1	1.5	1.2	1.1	1.5	1.0	1.4	1.4	1.3	1.0	1.1	1.0	1.0	1.0	1.6
Mn	0.10	0.088	0.065	0.021	0.083	0.15	0.033	0.055	0.068	0.073	0.065	0.03	0.034	0.036	0.017	0.093
*Fe	2.5	2.2	5.5	1.8	1.4	1.5	2.1	1.8	1.8	1.5	1.3	1.5	2.7	3.3	1.8	3.3
Co	0.10	0.018	0.02	0.02	0.01	0.012	0.01	0.018	0.06	0.01	0.01	0.01	0.01	0.01	0.01	0.02
Ni	0.46	0.025	0.23	0.11	0.11	0.067	0.066	0.17	0.28	0.074	0.025	0.060	0.045	0.62	0.045	0.13
Cu	0.23	0.11	0.15	0.31	0.24	0.20	0.38	0.20	0.22	0.096	0.19	0.30	0.10	0.12	0.17	0.29
Zn	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1	<1
Ga	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1
As	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1
Zr	0.14	0.02	0.15	0.12	0.050	0.22	0.048	0.13	0.15	0.38	0.12	0.14	0.045	0.025	0.025	0.10
Nb	0.027	0.13	0.11	0.047	0.037	0.041	0.065	0.092	0.025	0.019	0.045	0.045	0.021	0.021	0.014	0.019
Mo	0.25	0.24	0.24	0.18	0.37	0.29	0.29	0.29	0.15	0.18	0.26	0.29	0.15	0.25	0.23	0.29
Cd	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2	<0.2
Sn	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3	<0.3
Sb	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1	<0.1
Ba	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05
La	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05
Ce	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05
Hf	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01	<0.01
W	0.2	0.2	0.2	0.2	0.2	0.2	0.2	0.2	0.2	0.2	0.1	0.1	0.2	0.2	0.2	0.2
Pb	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05
Bi	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05	<0.05

ppm's of everything

Example of As-Grown Sample Data and Inference



Observations

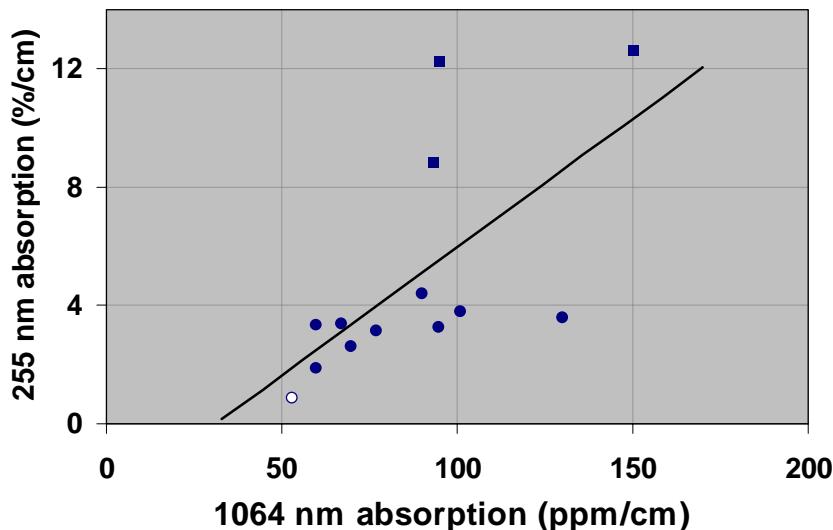
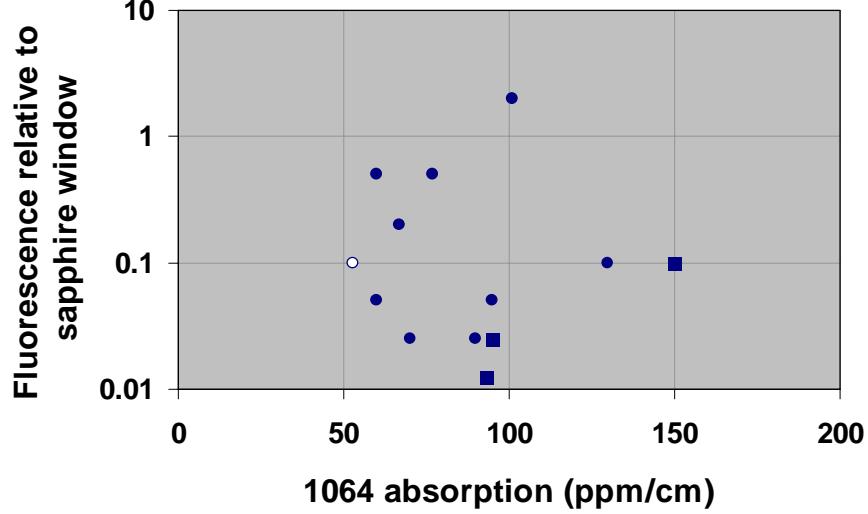
255 nm absorption correlates with 1064 nm
extrapolates to limit of 40 ppm
weaker correlation at high concentration
No correlation of 1064 nm absorption and Ti fluor.

Tentative Conclusions

F-center (or correlated defect) contributes to 1064 abs.
can drive this defect to negligible level
remaining 40 ppm from another defect
Ti not related to these defects

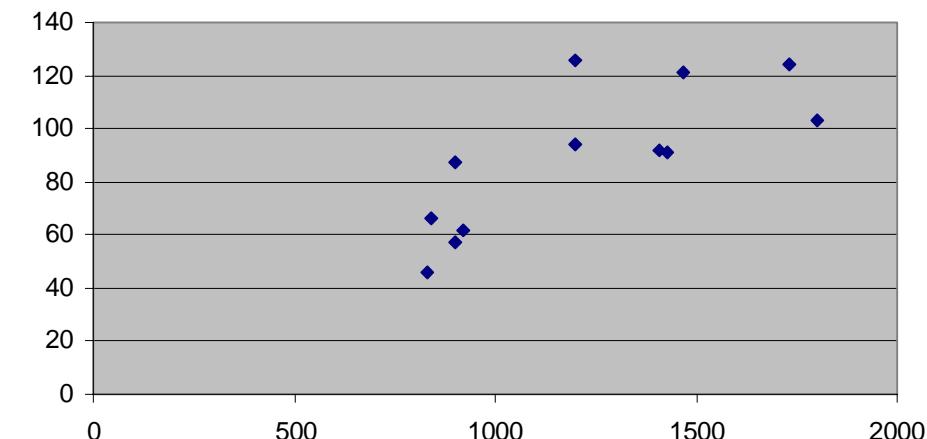
Typical of process for other observed correlations

Correlation of absorption in 255 nm band and at 1064 nm

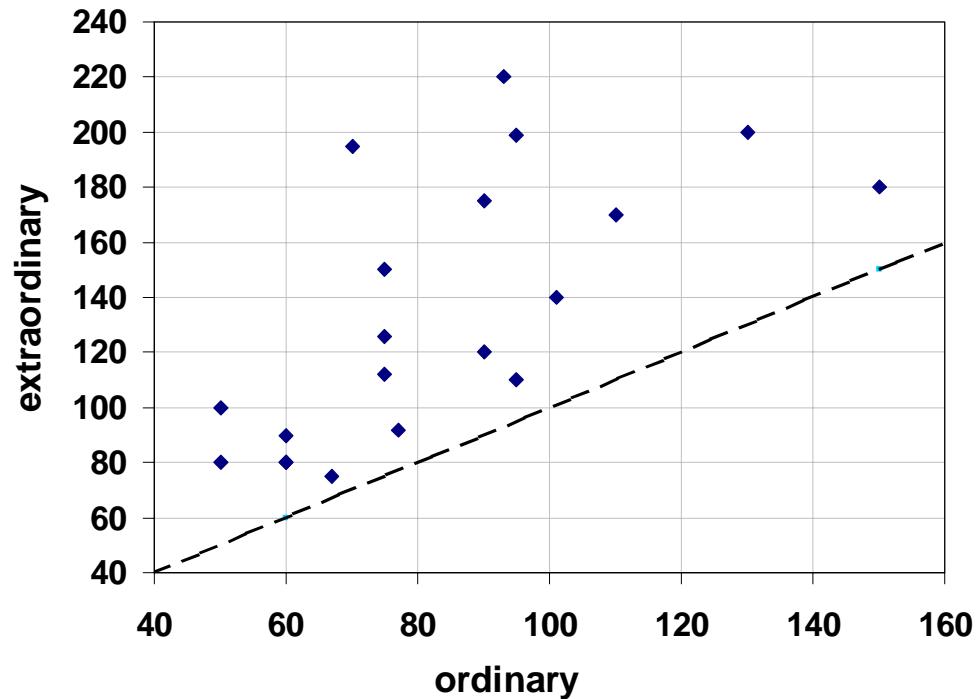


Other Typical Observations

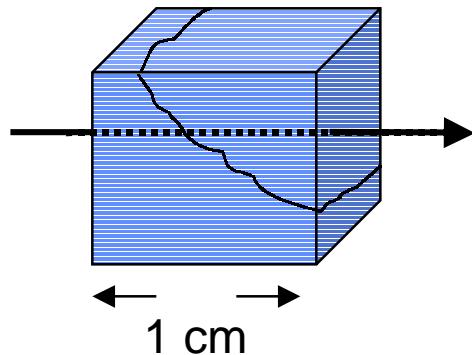
Absorption (ppm/cm) 1064 nm vs 532 nm, o-wave



**Absorption at 1064 nm (ppm/cm):
extraordinary vs ordinary**

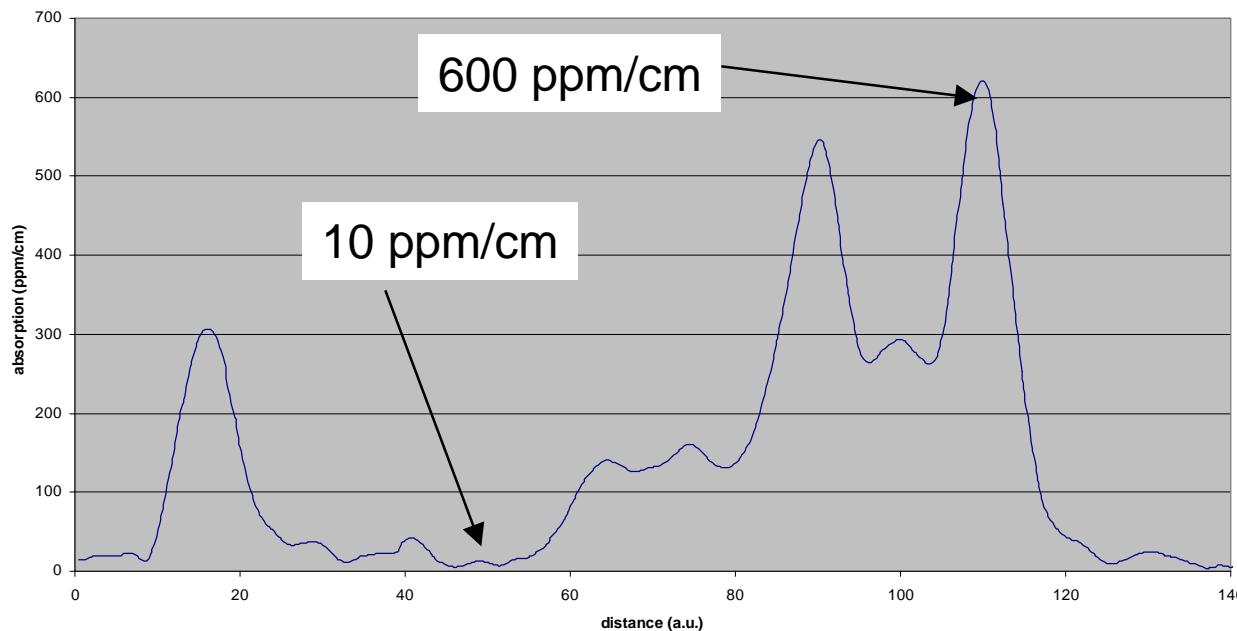


Curious observation (Rosetta Sapphire)

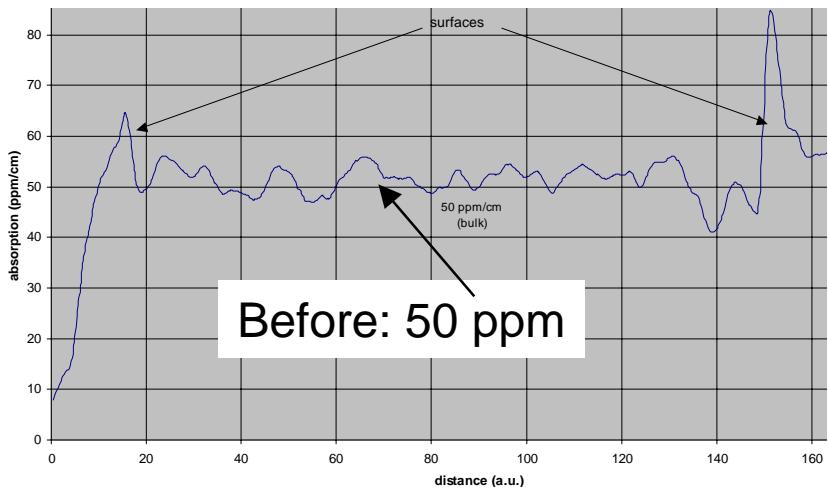


- Single 1 cm sample
 - region with 10 ppm/cm
 - region with 600 ppm/cm
 - abrupt boundary between
- Preparation unexceptional
- Tantalizing existence proof
- Mechanism not yet clear
 - suggests “self-normalizing” measurements

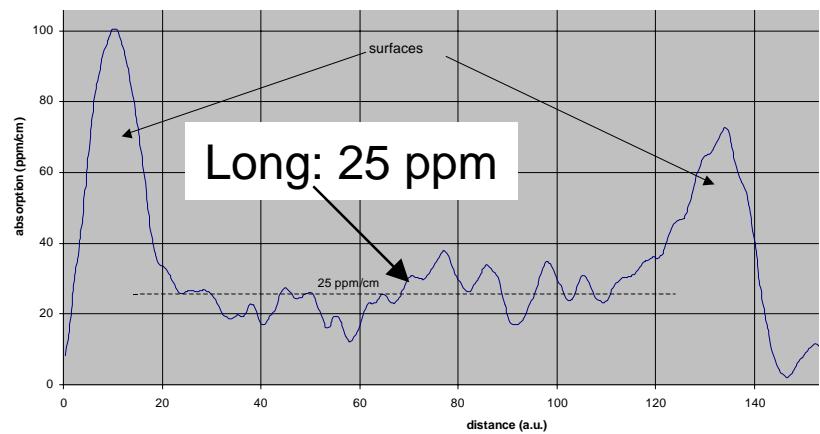
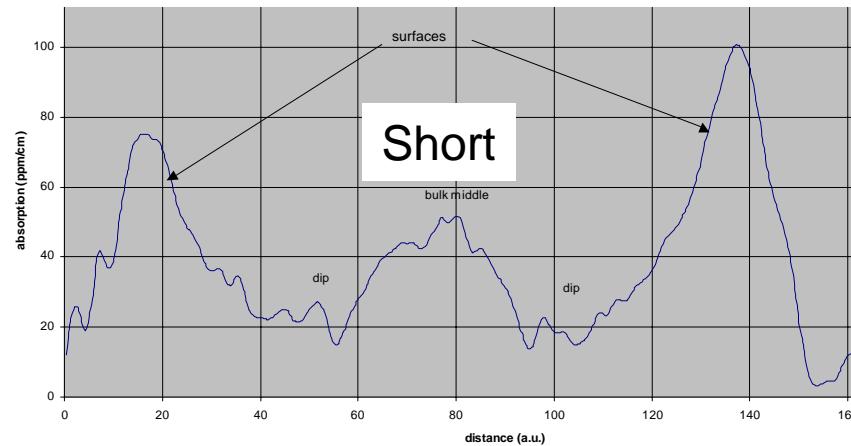
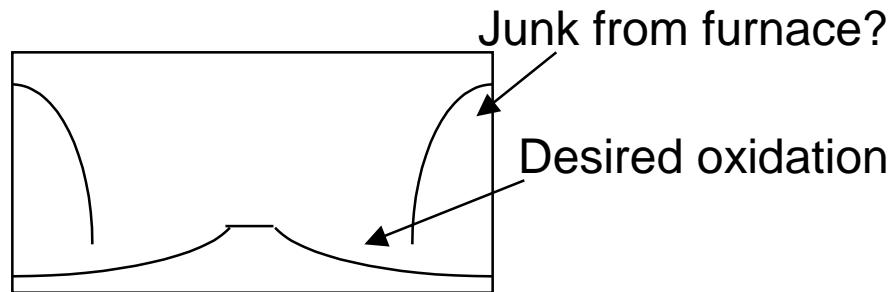
Sapphire cube 8T: IR scan across the scatter boundary (15 mm-long sample)



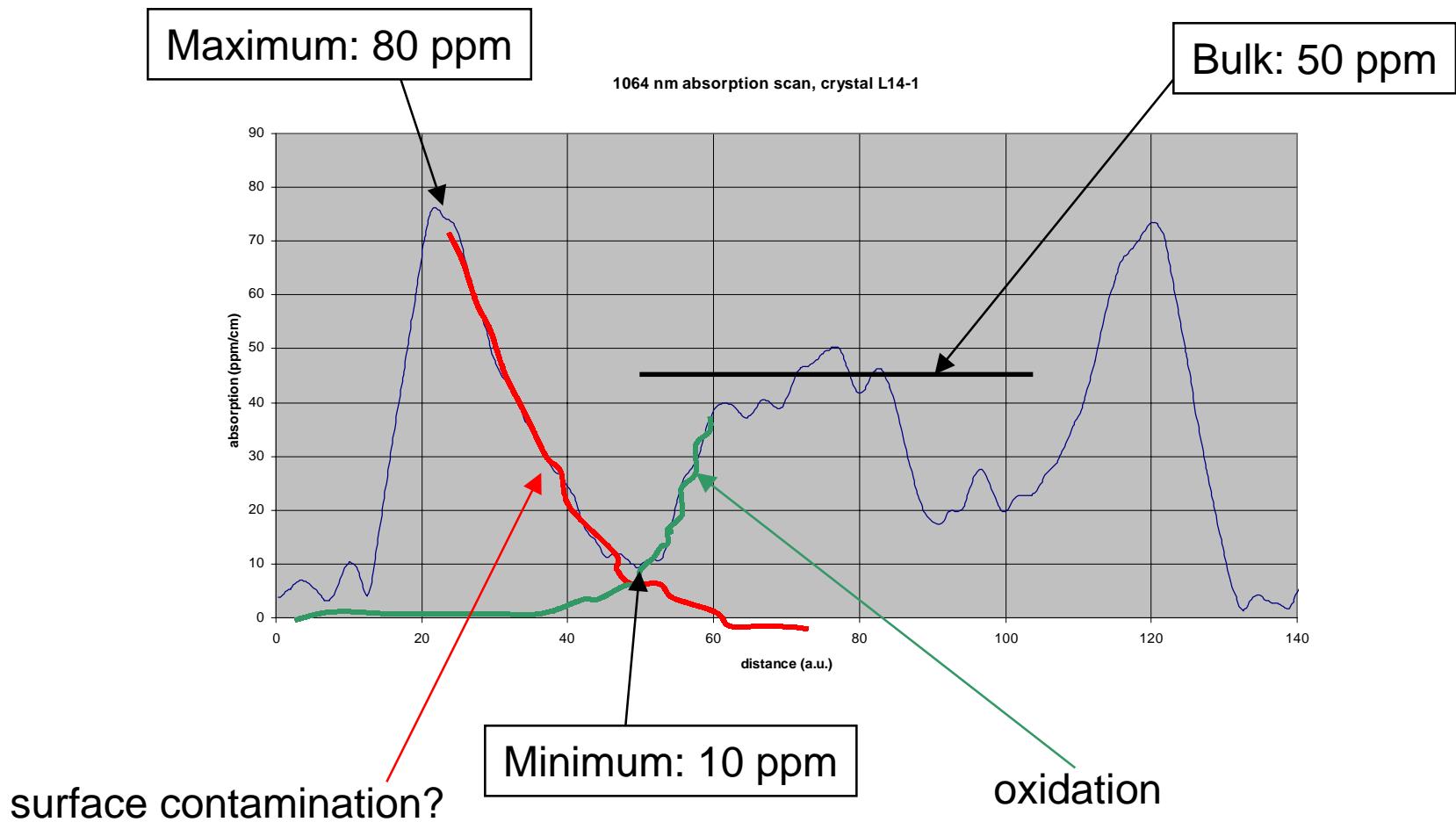
Typical Annealing results



- 1 cm thick window
- Two diffusion waves?



Complicated Annealing Phenomena



1064 nm absorption through cross-section of a cube

Annealed Samples Show Variety of Outcomes

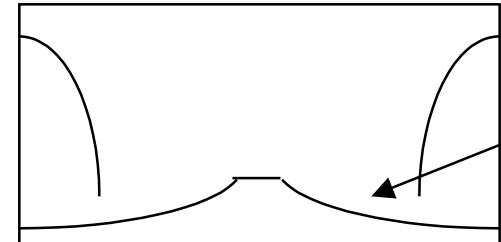
Anneal#	Crystal	Anneal	buk	dip	surface	buk	dip	surface	Scattering	Flor.^
1	LB-1	No	850-1300	no	no	50-60	no	no	no	1/2
1	LB-2	No	1200-1500	no	no	60-70	no	no	no	1/2
2	L14-1	1450C,48 hrs,air	1350	300	600	50	10-20	75	Near surfaces*	2^^
2	L14-2	1450C,48 hrs,air	800	300	2200	75	45	4000	Near surfaces*	1/2^^
3	L140 -1	1450C,48 hrs,air w /O 2 assist	1100	250	700	50-60	20	260	Near surfaces*	1/2^^
3	L140 -2	1450C,48 hrs,air w /O 2 assist	700	250	700	45	25	900	Near surfaces*	1/2^^
4	L16-1	1600C,48 hrs,air	80-170	no	350	25	no	90	Maximum in the bulk**	1/200
4	L16-2	1600C,48 hrs,air	170	no	500	35	no	140	Maximum in the bulk**	1/200
5	L160 -1	1600C,48 hrs,air w /O 2 assist	120	no	300	80	no	220	Maximum in the bulk**	1/200
5	L160 -2	1600C,48 hrs,air w /O 2 assist	200	no	375	90	no	300	Maximum in the bulk**	1/200
6	LH17-a	1750C,24 hrs,H2	600-1700	no	25000	60-170	no	37000	no	1/2^^
6	LH17-b	1750C,24 hrs,H2	1700	no	5000	125	no	250	no	1/2^^
7	L1696-1	1600C,96 hrs,air	300	no	450	50	no	140	Maximum in the bulk**	1/400
7	L1696-2	1600C,96 hrs,air	230	no	500	32	no	120	Maximum in the bulk**	1/300
8	L17H1696-1	1750C,24 hrs,H2+1600C,96hrs,air	300	no	1300	100	no	500	Maximum in the bulk**	1/400
8	L17H1696-2	1750C,24 hrs,H2+1600C,96hrs,air	230	no	900	35	no	250	Maximum in the bulk**	1/400
9	LN16-1	1600C,48 hrs,nitrogen	400	no	450	50	no	80	Maximum in the bulk**	<1/100
9	LN16-2	1600C,48 hrs,nitrogen	300	no	350	40	no	600	Maximum in the bulk**	<1/100
10	L169-1	1600C,48 hrs,air-900C hold 48 hrs during CD	3500	no	4000	550	no	1200	Weak in the bulk	<1/100
10	L169-2	1600C,48 hrs,air-900C hold 48 hrs during CD	700	no	800	150	no	165	Maximum in the bulk**	<1/100
11	LH14-1	1450C,48 hrs,hydrogen	650-800		1200-1300	40		70	no	
11	LH14-2	1450C,48 hrs,hydrogen	1750		2000	60		80	no	

*Relative to the reference 3 mm-thick window

similar table exists for as-grown cubes

Observed Trends

- Annealing
 - hydrogen annealing does not affect bulk absorption
 - oxygen annealing appears to reduce bulk absorption
 - surface contamination appears to limit final outcome
 - two diffusion “waves”: one reduces loss, one increases it
- No strong correlation with starting material
 - native defect?
 - furnace contamination?
- No strong correlation with position in boule or remelt
 - native defect?
 - furnace contamination?
 - multiple impurities?



Status/ Plans

- Currently:
 - ~ 40 ppm/cm ~reproducible
 - 25 ppm/cm observed in macroscopic volumes
 - 10 ppm/cm in isolated regions
- Next steps:
 - elimination of surface effects essential for reproducible studies
 - new annealing furnace (CSI and SU)
 - more careful surface prep and absorption measurement prior to annealing
 - repeat best annealing conditions w/o surface contamination “wave”
 - revisit impurity correlations after reproducible annealing
 - neutron activation with Southern U. (McGuire)
 - multiwavelength PCI
 - “solid-state electrolysis” from General Physics Institute (Danileiko)?